



Product Summary

BV _{DSS}	Rds(on) Max	Ι _D Tc = +25°C
100V	16mΩ @ V _{GS} = 10V	44A
1000	18mΩ @ V _{GS} = 6V	41A

Description

This new generation N-Channel Enhancement Mode MOSFET is designed to minimize R_{DS(ON)} yet maintain superior switching performance. This device is ideal for use in notebook battery power management and load switch.

Applications

- Motor controls
- DC-DC converters
- Power managements

Features

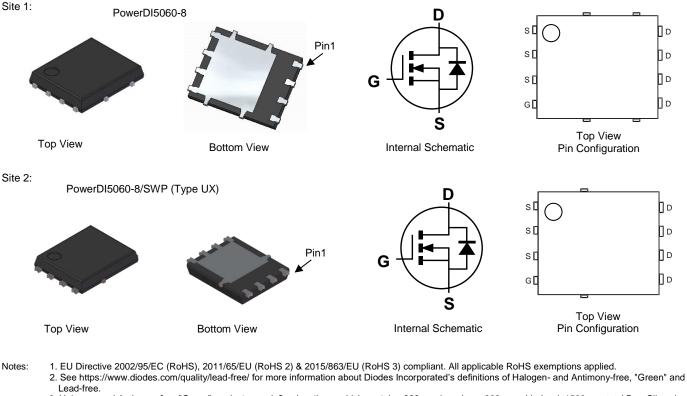
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- High Conversion Efficiency
- Low RDS(ON) Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotiveproducts/.

 This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Lead-Frame. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)



3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

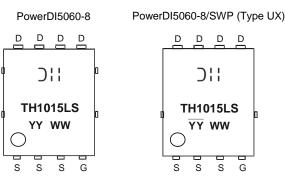


Ordering Information (Note 4)

Part Number	Package	Pad	Packing		
Fait Nulliber	Fackage	Qty.	Carrier		
DMTH10H015LPS-13	PowerDI5060-8	2,500	Tape & Reel		
DMTH10H015LPS-13	PowerDI5060-8/SWP (Type UX)	2,500	Tape & Reel		

Note: 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage	VDSS	100	V		
Gate-Source Voltage			V _{GSS}	±20	V
	Steady State	T _A = +25°C T _A = +70°C	lo	11 8	A
Continuous Drain Current (Note 5) $V_{GS} = 10V$	Steady State	T _C = +25°C T _C = +100°C	lo	44 28	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	•	I _{DM}	120	А	
Maximum Continuous Body Diode Forward Current (N	ls	1.5	А		
Avalanche Current (Note 7) L = 3mH			las	7.5	А
Avalanche Energy (Note 7) L = 3mH			E _{AS}	85	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	2.8	W
Thermal Resistance, Junction to Ambient (Note 5)		Reja	52	°C/W
Total Power Dissipation	Tc = +25°C	PD	46	W
Thermal Resistance, Junction to Case		R _{0JC}	2.7	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

Short duration pulse test used to minimize self-heating effect.

7. Guaranteed by design. Not subject to product testing.



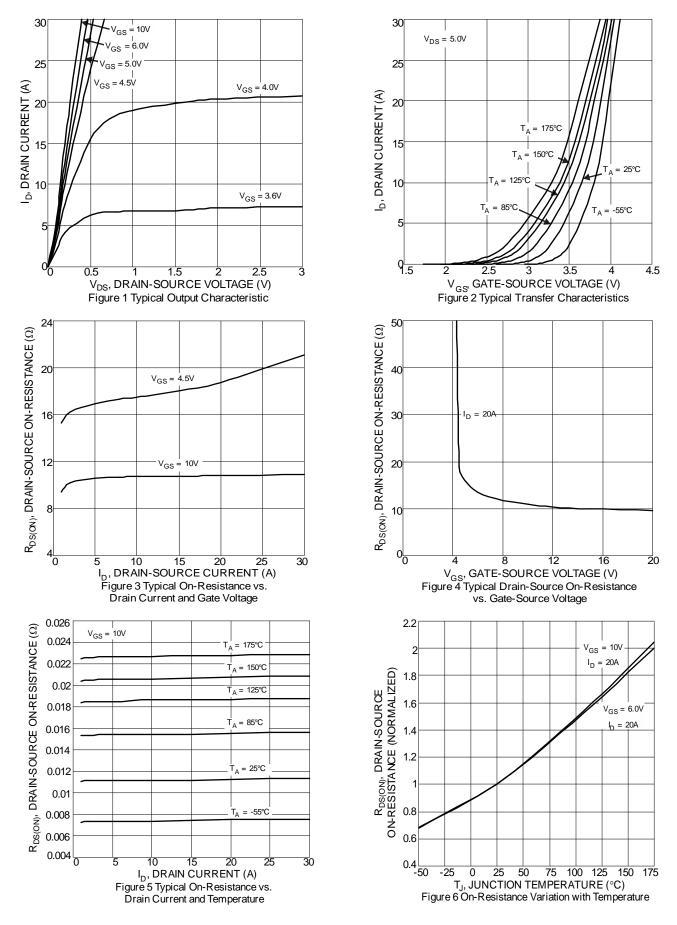
Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)						
Drain-Source Breakdown Voltage	BVDSS	100			V	$V_{GS} = 0V, I_D = 1mA$
Zero Gate Voltage Drain Current	IDSS	_	_	1	μA	$V_{DS} = 80V, V_{GS} = 0V$
Gate-Source Leakage	lgss		_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 6)						
Gate Threshold Voltage	V _{GS(TH)}	1.4	2	3	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
		—	11	16		V _{GS} = 10V, I _D = 20A
Static Drain-Source On-Resistance	Rds(on)	—	13.5	18	mΩ	VGS = 6V, ID = 20A
		—	18.4	25		$V_{GS} = 4.5V, I_D = 5A$
Diode Forward Voltage	Vsd	—	0.9	1.3	V	V _{GS} = 0V, I _S = 20A
DYNAMIC CHARACTERISTICS (Note 7)						
Input Capacitance	Ciss	—	1,871	_	pF	$V_{DS} = 50V, V_{GS} = 0V$ f = 1MHz
Output Capacitance	Coss	—	261	—		
Reverse Transfer Capacitance	Crss	—	7	_		
Gate Resistance	Rg	—	0.75	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge	Qg	—	33.3	—		VD = 50V. ID = 10A.
Gate-Source Charge	Qgs	—	6.9	_	nC	$V_{DD} = 50V, ID = 10A,$ $V_{GS} = 10V$
Gate-Drain Charge	Q _{gd}	—	5.1	_		
Turn-On Delay Time	t _{D(ON)}	_	6.5	_		$V_{DD} = 50V, V_{GS} = 10V,$ $I_D = 10A, R_G = 6\Omega$
Turn-On Rise Time	tR	_	7	_	ns	
Turn-Off Delay Time	tD(OFF)	_	19.7			
Turn-Off Fall Time	tF	_	8.1]	
Reverse Recovery Time	trr	_	37.9		ns	
Reverse Recovery Charge	Q _{RR}		51.9		nC	IF = 10A, di/dt = 100A/μs

6. Short duration pulse test used to minimize self-heating effect.7. Guaranteed by design. Not subject to product testing. Notes:

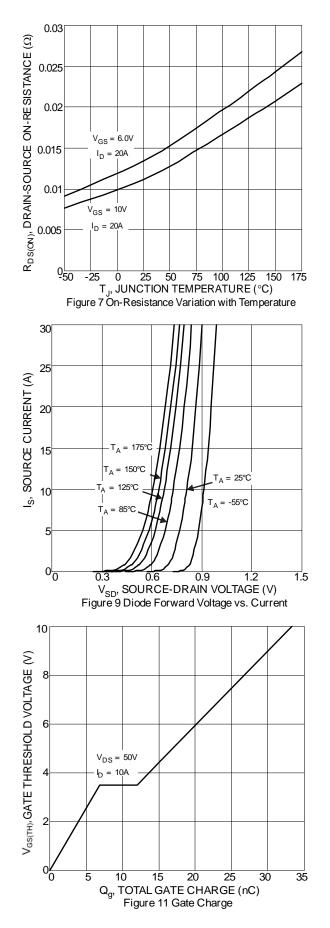


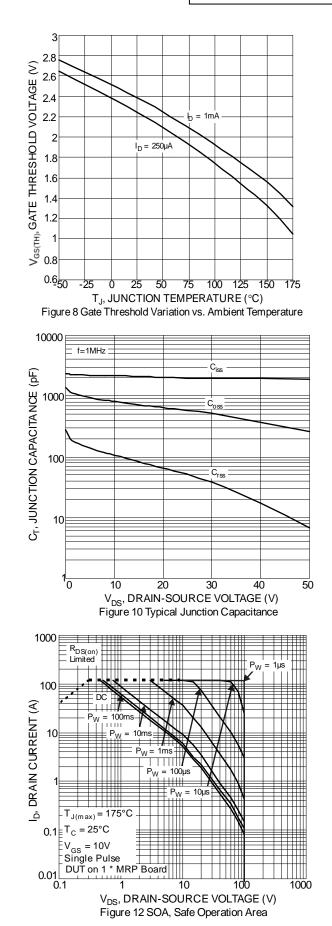
DMTH10H015LPS



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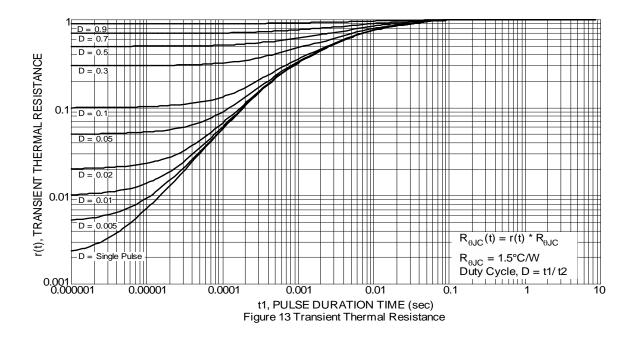






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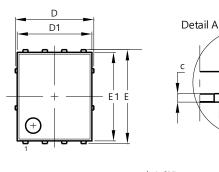




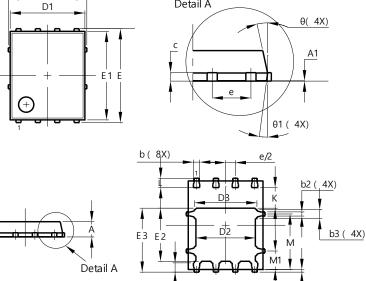
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

Site 1:



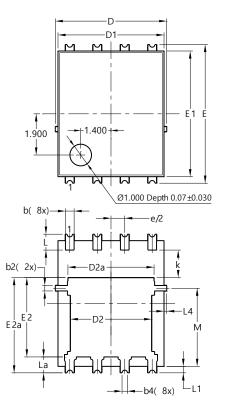




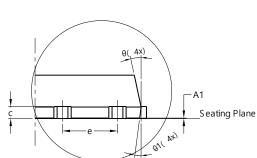
G

PowerDI5060-8				
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A1	0.00	0.05	-	
b	0.33	0.51	0.41	
b2	0.200	0.350	0.273	
b3	0.40	0.80	0.60	
С	0.230	0.330	0.277	
D		5.15 BSC		
D1	4.70	5.10	4.90	
D2	3.70	4.10	3.90	
D3	3.90	4.30	4.10	
ш	(6.15 BSC	;	
E1	5.60	6.00	5.80	
E2	3.28	3.68	3.48	
E3	3.99	4.39	4.19	
е		1.27 BSC	;	
G	0.51	0.71	0.61	
ĸ	0.51	-	-	
L	0.51	0.71	0.61	
L1	0.100	0.200	0.175	
М	3.235	4.035	3.635	
M1	1.00	1.40	1.21	
Θ	10°	12°	11°	
Θ1	6°	8°	7°	
All	All Dimensions in mm			

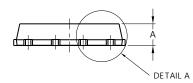
Site 2:



PowerDI5060-8/SWP (Type UX)



DETAIL A



PowerDI5060-8/SWP (Type UX)				
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A1	0	0.05		
b	0.30	0.50	0.41	
b2	0.20	0.35	0.25	
b4	().25REF	-	
С	0.230	0.330	0.277	
D	5	.15 BS0	2	
D1	4.70	5.10	4.90	
D2	3.56	3.96	3.76	
D2a	3.78	4.18	3.98	
E	6	6.40 BS0	2	
E1	5.60	6.00	5.80	
E2	3.46	3.86	3.66	
E2a	4.195	4.595	4.395	
е		1.27BSC)	
k	1.05		-	
L	0.635	0.835	0.735	
La	0.635	0.835	0.735	
L1	0.200	0.400	0.300	
L1a	0	.050RE	F	
L4	0.025	0.225	0.125	
М	3.205	4.005	3.605	
θ	10°	12°	11°	
θ1	6°	8°	7°	
All	All Dimensions in mm			

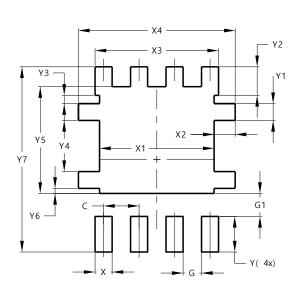
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Suggested Pad Layout

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Site 1:

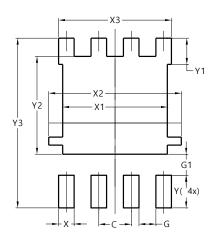


Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

Site 2:

PowerDI5060-8/SWP (Type UX)

PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	5.190
X3	4.420
Y	1.270
Y1	1.020
Y2	3.810
Y3	6.610

s.com/package-outlines.htm



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